



MgB₂ coating by HPCVD for 1.3 GHz superconducting RF cavities

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U.S. DEPARTMENT OF
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MgB₂: Higher T_c , Potentially Low RF loss and High Gradient

	Nb	MgB ₂
T_c (K)	9.2	40
ρ_0 ($\mu\Omega$ cm)	5	0.1
Δ (meV)	1.5	7 (σ), 2(π)
$B_c(0)$ (T)	0.20	possibly 0.80
$B_{c1}(0)$ (T)	0.17	<0.1

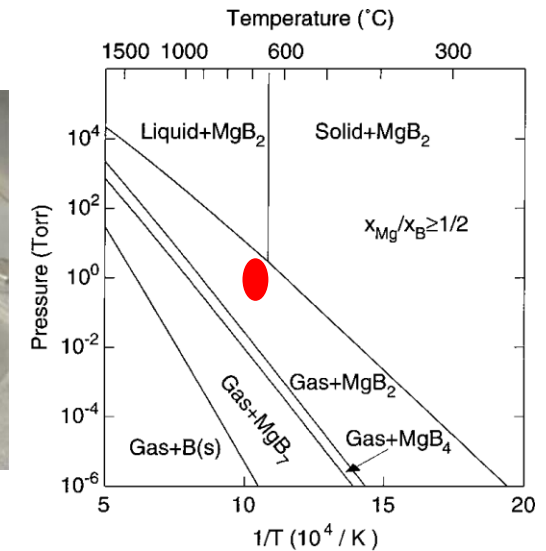
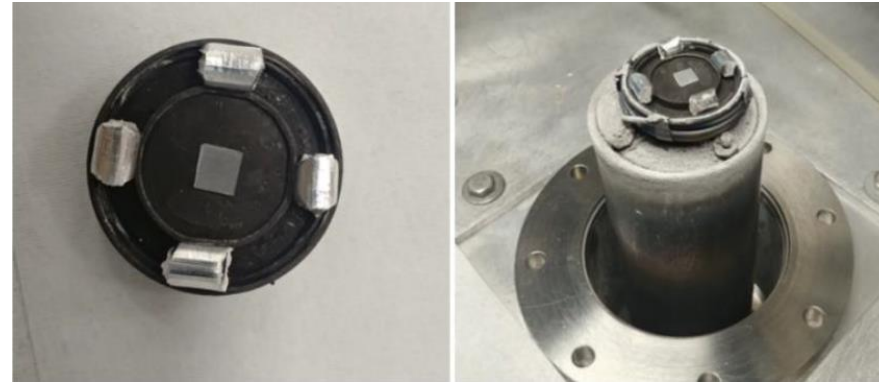
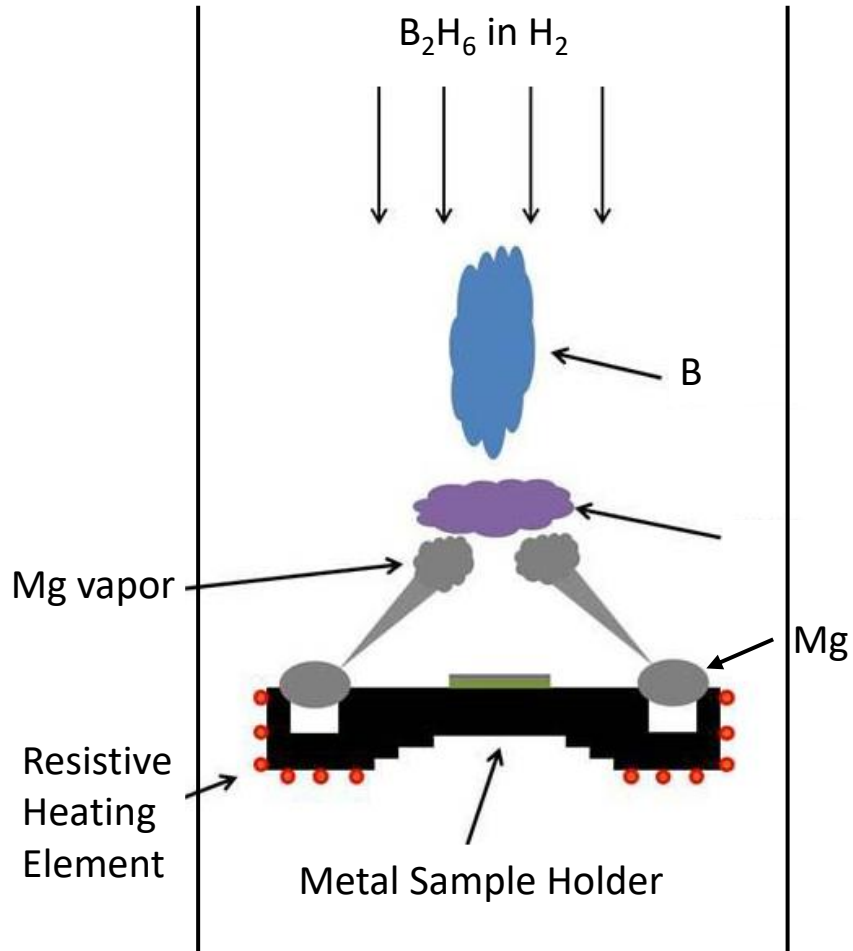
Potential to operate at 10-20 K with similar or higher energy gradient than Nb.

— RF surface resistance depends on energy gap and residual resistivity. Larger gap and lower resistivity indicate potential low RF loss than in Nb.

— Field gradient is ultimately limited by thermodynamic critical field. For MgB₂, $B_c(0)$ could be as high as 800 mT, vs. 200 mT for Nb.

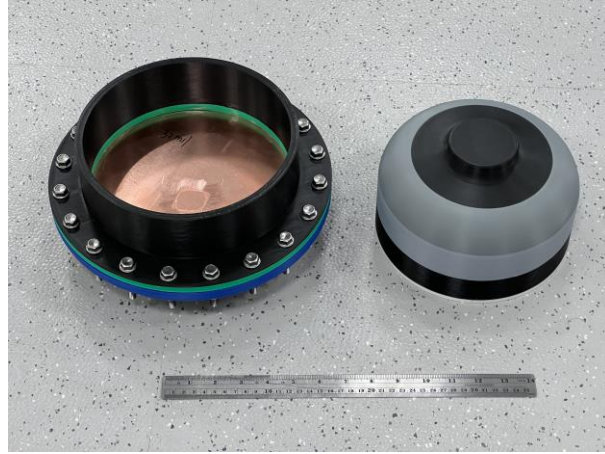
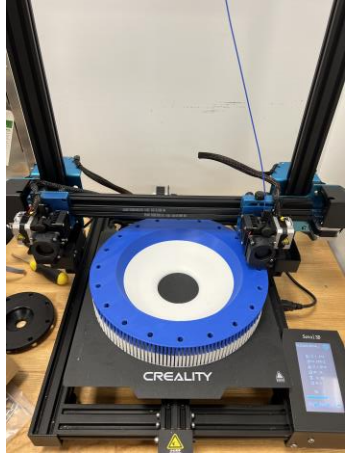
— Lower critical field $B_{c1}(0)$ may be an obstacle.

Growth of MgB_2 Films by HPCVD (Hybrid Physical-Chemical Vapor Deposition)

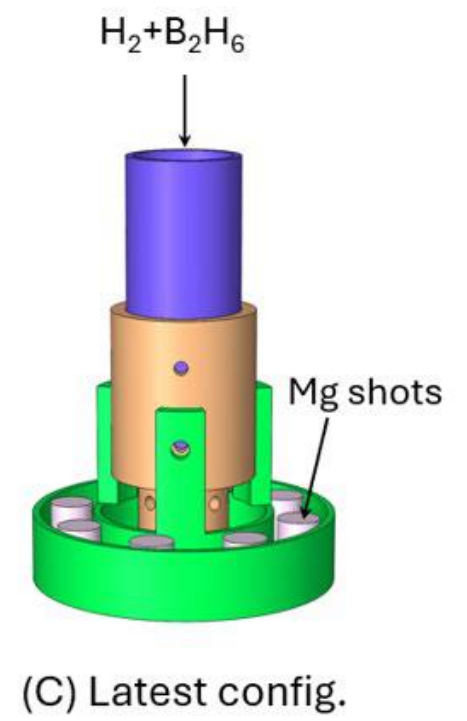
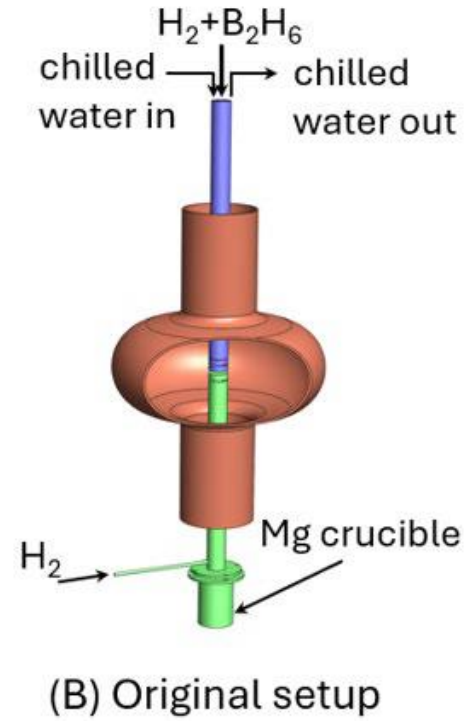
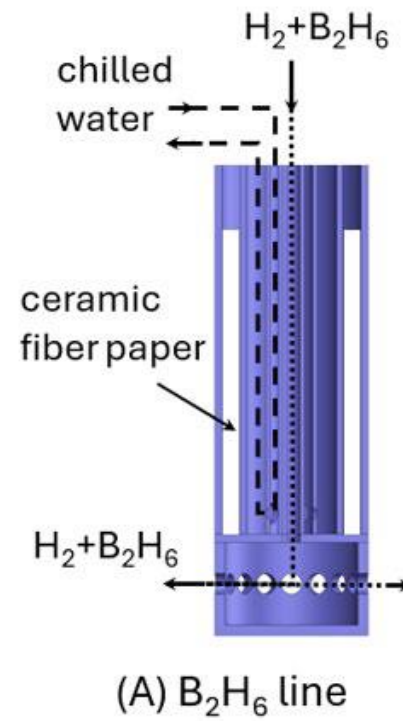


- Evaporation of Mg pellets provides high-pressure Mg vapor needed (physical vapor)
- Thermal decomposition of B_2H_6 provides pure B (chemical vapor)
- Presence of H_2 prevents oxidation of Mg
- Metal sample holder is made from stainless steel or molybdenum.
- Substrate materials: SiC (0001), Al_2O_3 (0001), MgO (111), etc. for epitaxial films and Ta, Mo, Cr, stainless steel, Cu, Si, etc. for polycrystalline films.

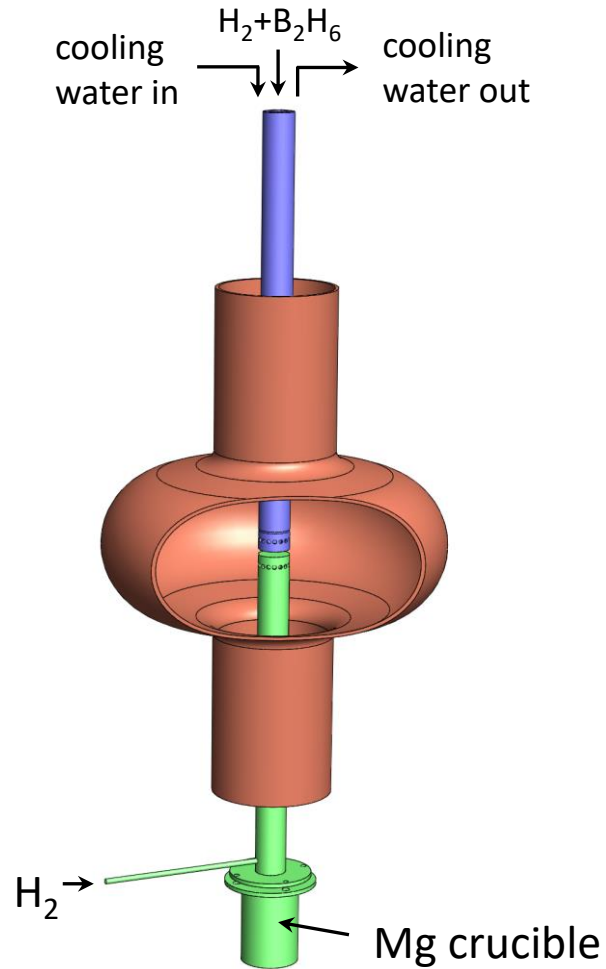
Fabrication of mock cavities



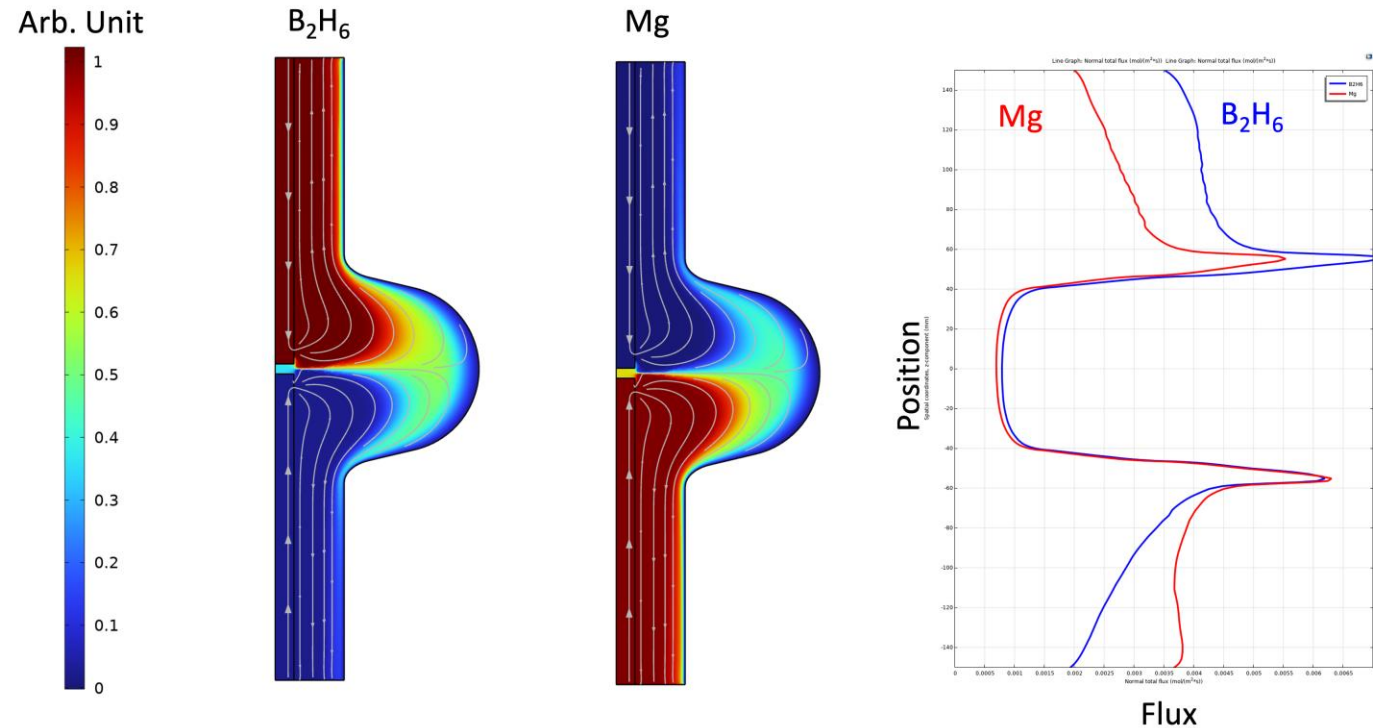
HPCVD Coating system



Simulation



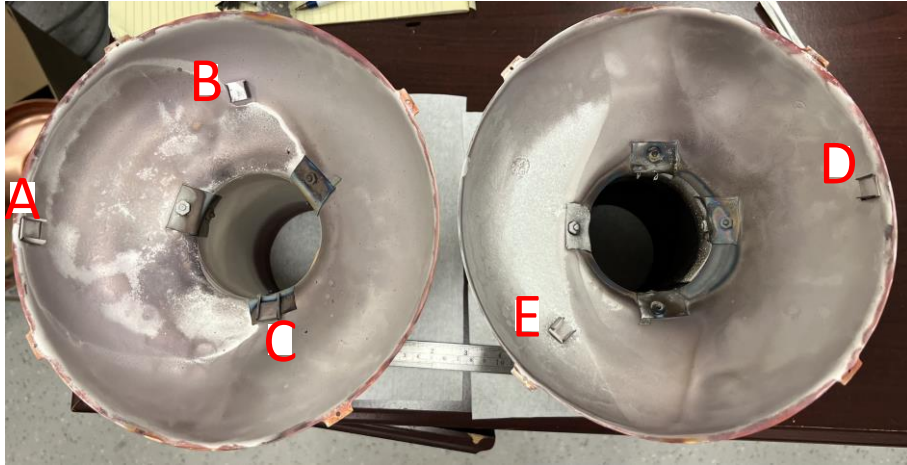
Simulated concentration distribution and flux rates on the cavity



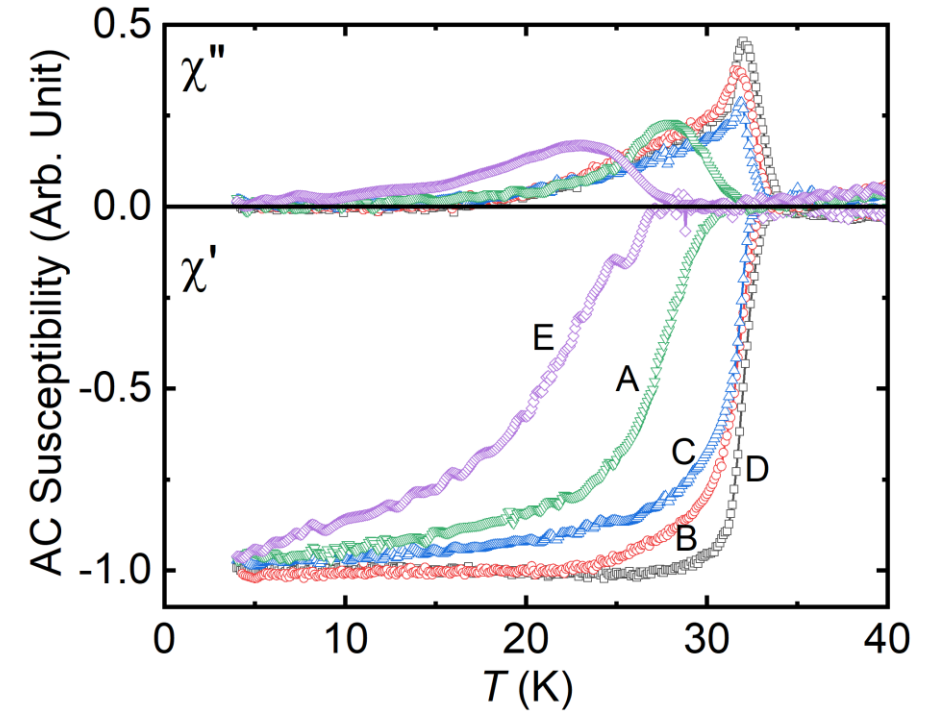
Colors: concentration Streamlines: velocity field

- By adjusting pressure and flow rates of the H_2 carrier gas, MgB_2 film can be coated inside the cavity with higher rate at the iris region than the equator region.
- Moving B and Mg sources vertically may be necessary to achieve needed uniformity.

AC susceptibility measurement of small samples



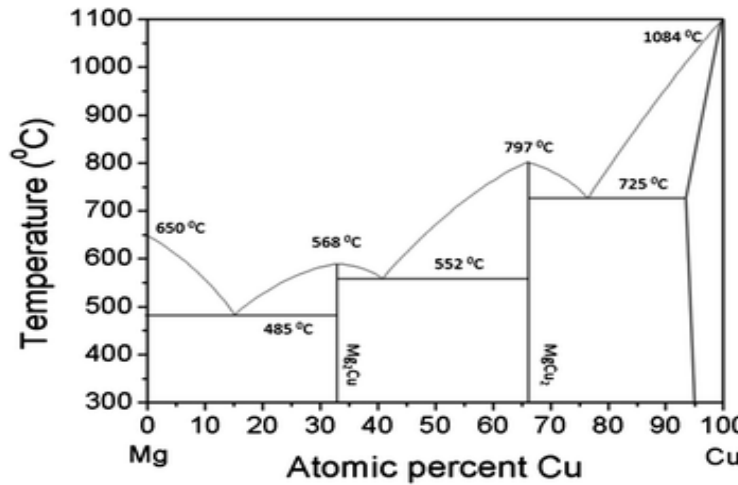
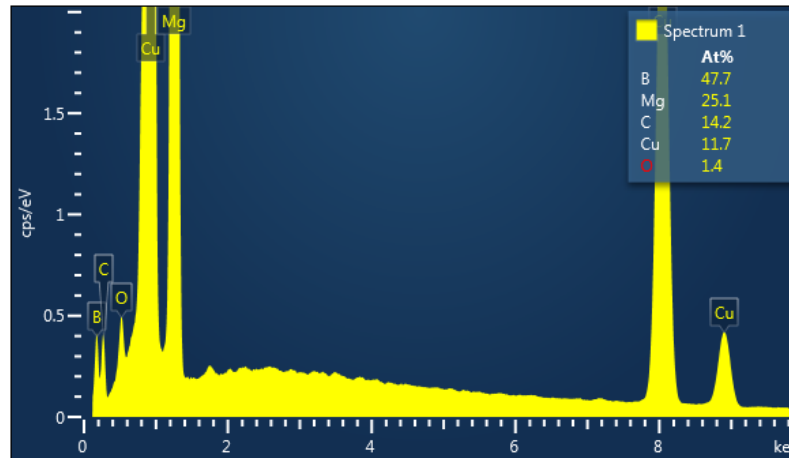
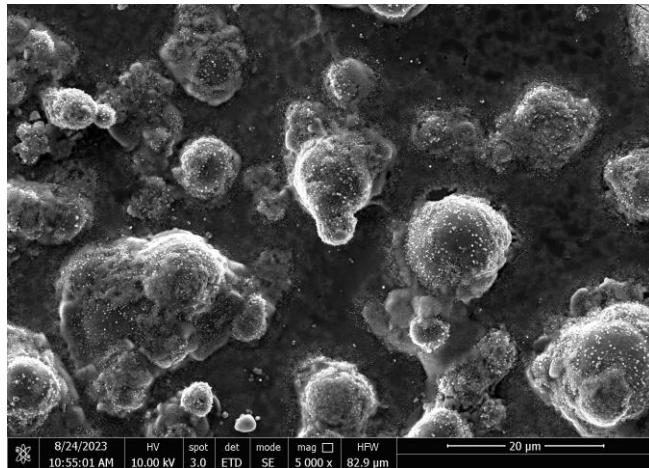
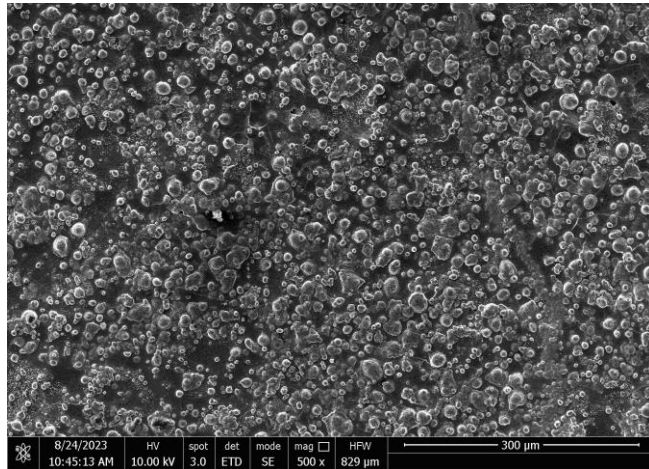
Sample	Position	T_c (K)
A	Top-half, equator	32.2
B	Top-half, middle	33.2
C	Top-half, iris	33.2
D	Bottom-half, equator	34.3
E	Bottom-half, middle	28.4



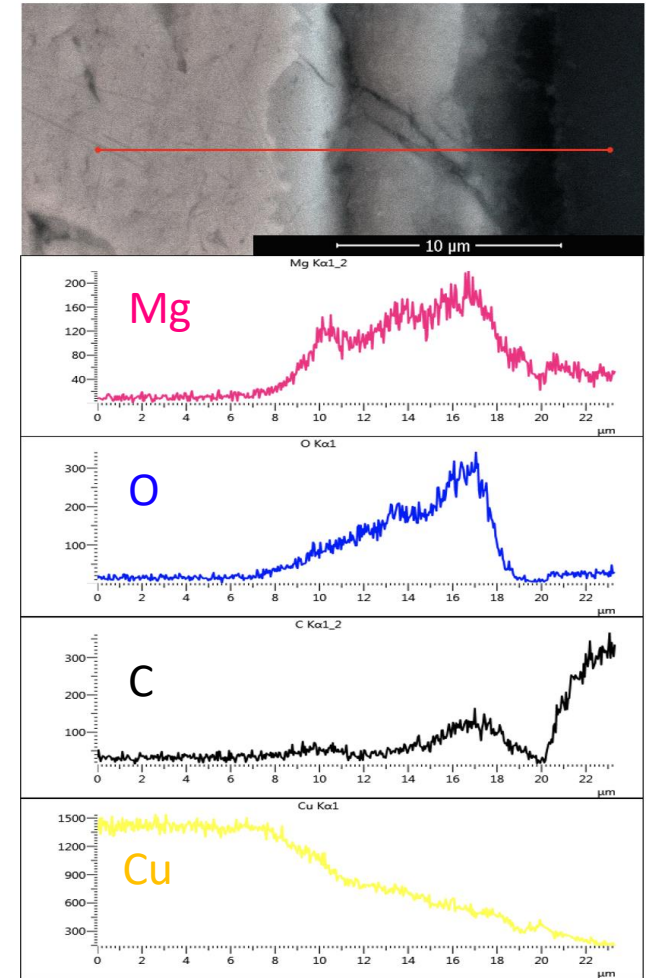
Lower T_{c0} than best MgB_2 on Cu sample (38K) not in a cavity setting is still under investigation.

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SEM Characterization of Small Samples



Cross section view



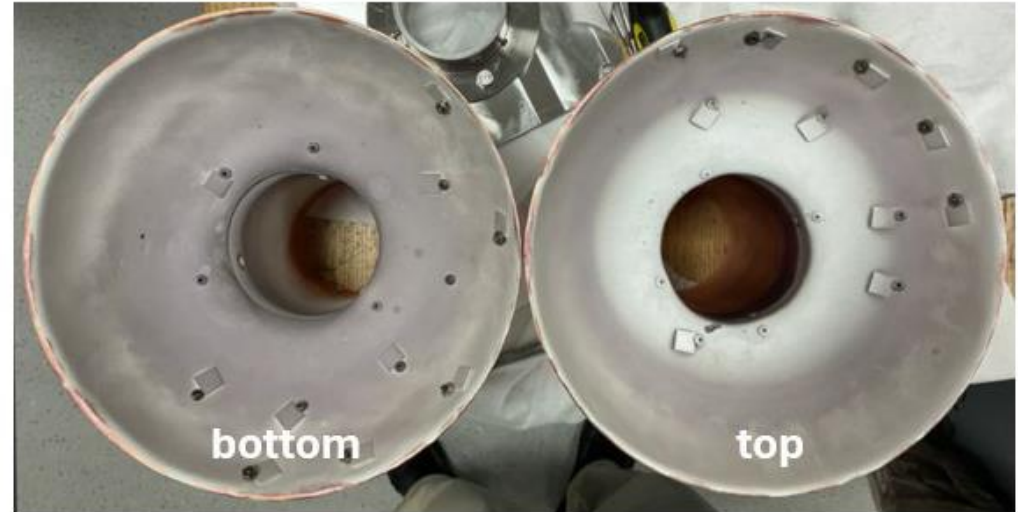
SEM/EDS shows a 10μm thick MgB_2 film grains grow on top of Mg-Cu alloy layer.

Improve film qualities by new B₂H₆ and Mg delivery designs



Currently being tested.

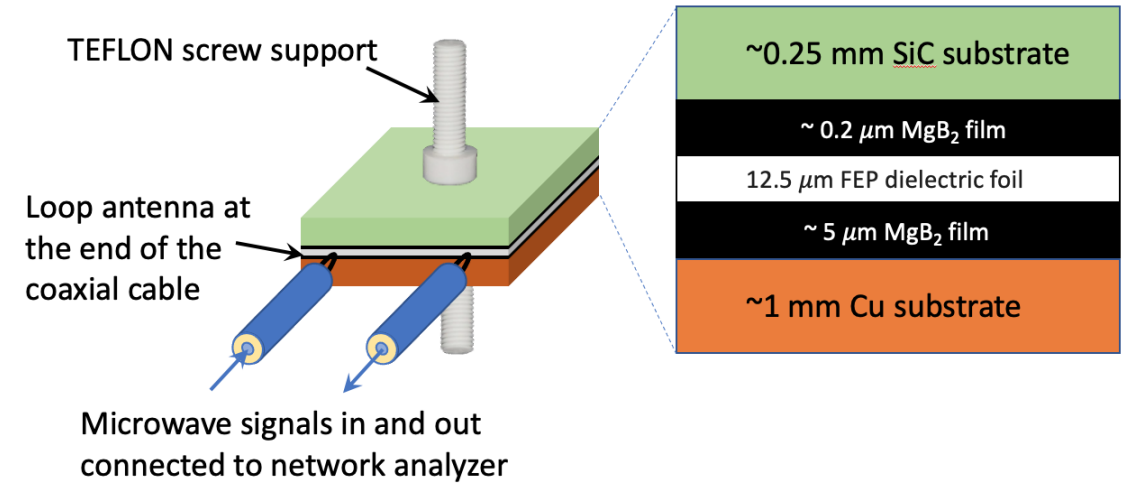
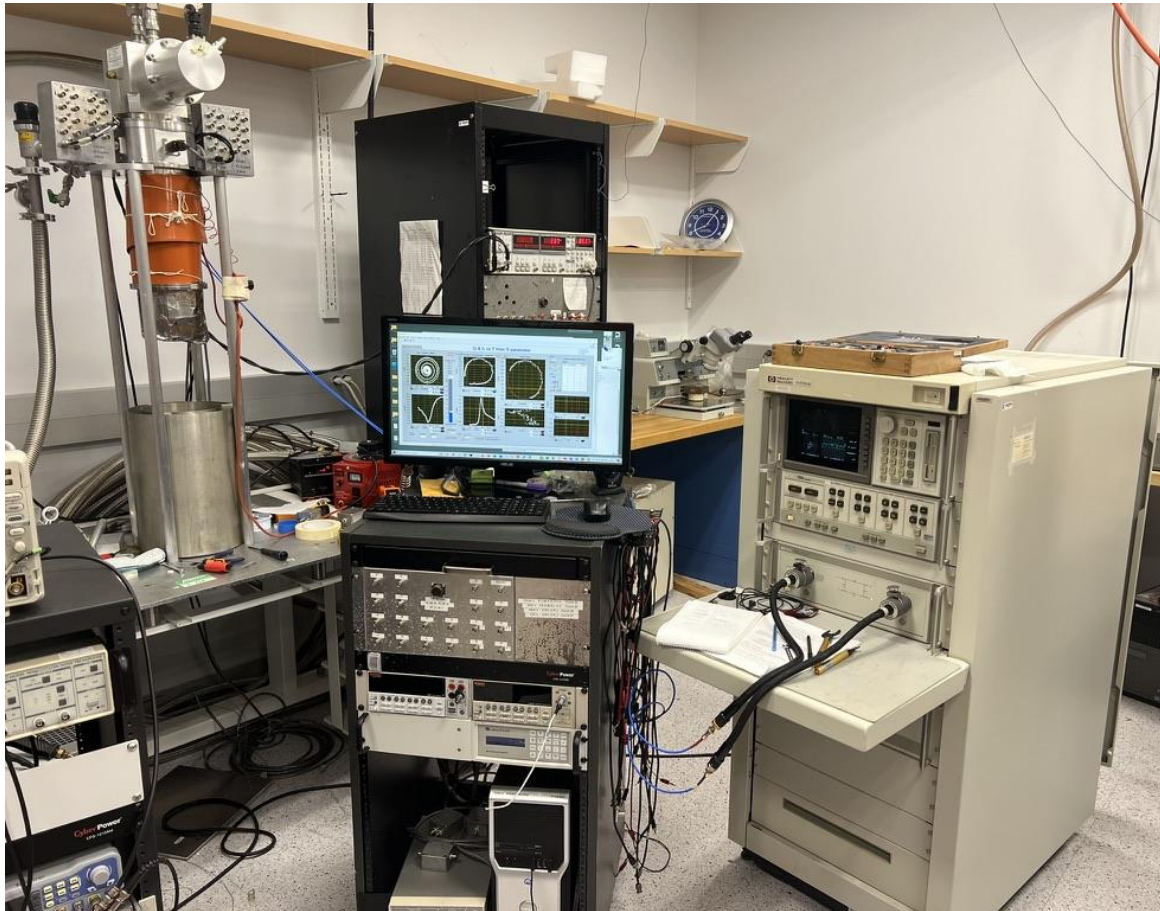
Mg heater supported from the bottom, therefore no blocking of B and Mg by three supporting arms.



B and Mg sources vertical movement of up to 20 cm achieved, which helps to coat film inside the neck cylinders.

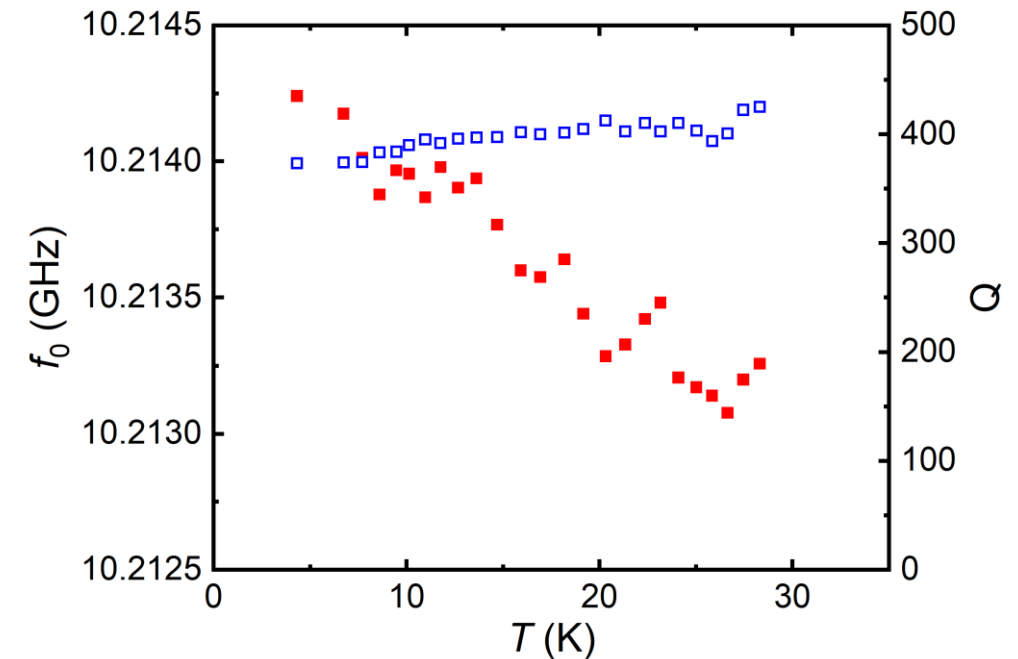
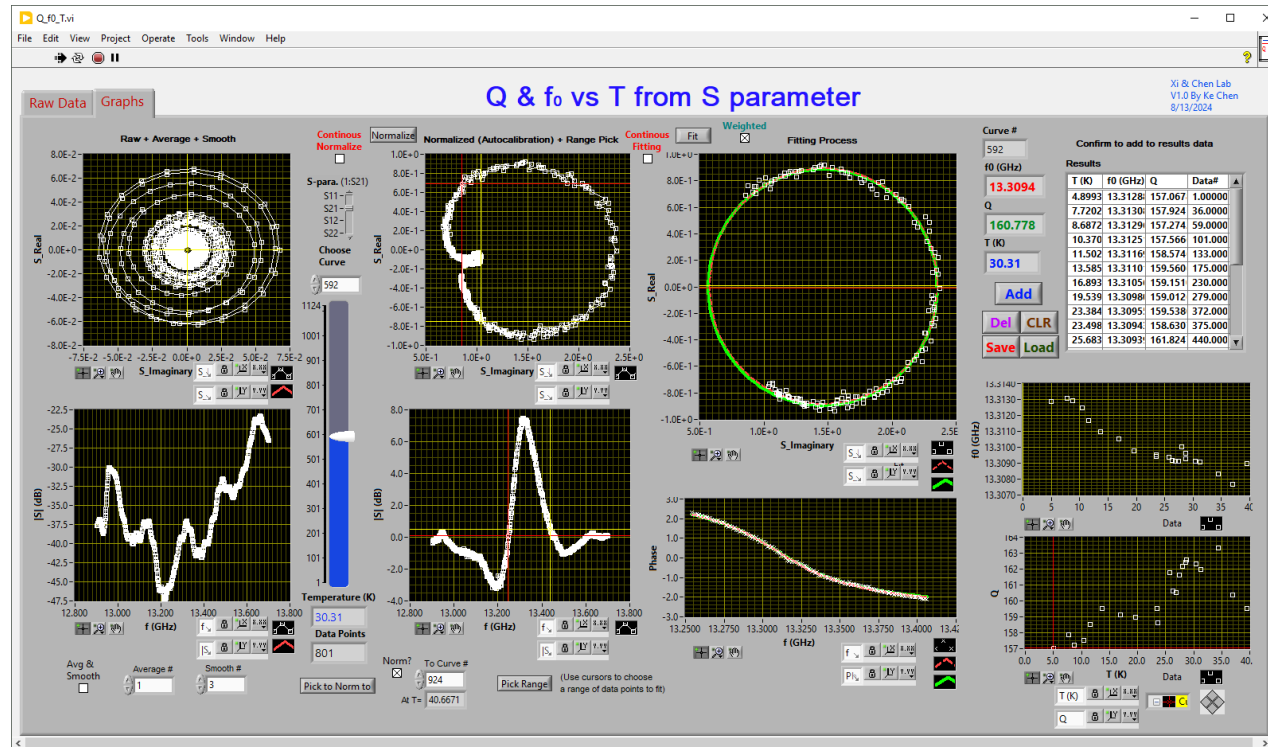
A new computer controlled moving flange up to 50 cm is expected to arrive in November 2024.

Microwave properties measurement using parallel plate resonator



Data analysis and preliminary data

MgB₂/SiC /FEP/ MgB₂/Cu
Parallel plate resonator



The resonance frequency is close to the TM01 mode of the 10mm x 10mm parallel plate resonator, and it increases as temperature decreases, in agreement with the fact that the penetration depth and hence the kinetic inductance is smaller at lower temperatures, confirming what measured was the mode of the superconducting parallel plate resonator.

Summary

- MgB₂ films coated on mock 1.3 GHz Cu RF cavities by HPCVD with T_{c0} as high as 34.2 K measured by AC susceptibility.
- Microwave measurements for surface resistance and power handling are being investigated.
- Coating uniformity across the whole cavity is being improved by revising the B and Mg delivery.

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